



High Efficiency 5.5V, 6A, 2.4MHz I²C Programmable, Synchronous Step Down Regulator *Preliminary Specification*

General Description

SY8827E is a high efficiency 2.4MHz synchronous step down DC/DC regulator IC capable of delivering up to 6A output currents. It can operate over a wide input voltage range from 2.5V to 5.5V and integrate main switch and synchronous switch with very low $R_{DS (ON)}$ to minimize the conduction loss. The output voltage can be programmed from 0.6V to 1.3875V through I²C interface.

SY8827E is in a space saving, low profile CSP1.56*1.96-20 package.

Ordering Information



Ordering Number	Package Type	Note 👩
SY8827EPKC	CSP1.56*1.96-20	6A
	c.s.	<u> </u>
		<u> </u>

Features

- Input voltage range: 2.5V to 5.5V
- 2.4 MHz switching frequency minimizes the external components
- Typical 65uA quiescent current
- Low $R_{DS(ON)}$ for internal switches (PFET/NFET): $28m\Omega/17m\Omega$
- Programmable Output Voltage: 0.6V to 1.3875V in 12.5mV steps
- 6A continuous output current capability.
- Capable for 0.25uH inductor and 22uF Ceramic Capacitor.
- Hie-cup mode protection for hard short condition
- RoHS Compliant and Halogen Free
- Compact package: CSP1.56*1.96-20

Applications

- Smart-phone
- Web-tablets

Typical Applications



Figure 1. Schematic Diagram

Figure2. Efficiency



Pinout (top view)



Note 1: x=year code, y=week code, z= lot number code.

Pin	Pin Name	Pin Description
D1,D2,E1,E2	VIN	Power input pin. These pins must be decoupled to ground with at least
		22uF ceramic capacitor. The input capacitor should be placed as close
		as possible between VIN and GND pins.
D3,D4,E3,E4	SW	Switching node pin. Connect these pins to the switching node of
		inductor.
B2,B3,C1,C2,C3,C4	GND	Power ground pins.
A1	VSEL	Voltage select pin. When this pin is low, V_{OUT} is set by the VSEL0
	•••	register. When this pin is high, V_{OUT} is set by the VSEL1 register.
A2	EN	Enable control pin. Active high. Do not leave it floating.
B1	SDA	I ² C interface Bi-directional Data line.
B4	AGND	Analog ground pin.
A3	SCL	I ² C interface clock line.
A4	VOUT	Sense pin for output. Connect to the output capacitor side.



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Absolute Maximum Ratings (Note 1)

/IN	6.0
All Other Pins	VIN + 0.6
Power Dissipation, PD @ TA = 25°C CSP1.56*1.96-20	2.61
Package Thermal Resistance (Note 2)	
θ _{JA}	38°C/W
θ _{JC}	8°C/V
function Temperature Range	150°C
Lead Temperature (Soldering, 10 sec.)	
Storage Temperature Range	
ESD Susceptibility (Note 2)	
Recommended Operating Conditions (Note 3)	100
Supply Input Voltage	2.5V to 5.5
Dutput Voltage	2.5V to 5
Ambient Temperature Range	40°C to 85°
c.O [℃]	
c_{0}	
$c^{(1)}$	
Ambient Temperature Range	
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Electrical Characteristics

(VIN = 5V, VOUT = 2.5V, L = 0.33uH, COUT = 22uF, TA = 25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Input Voltage Range	V_{IN}		2.5		5.5	V
V _{IN} UVLO	V _{UVLO}	V _{IN} Rising		2.35	2.45	V
V _{IN} UVLO Hysteresis	V _{UVHYST}			150		mV
Quiescent Current	IQ	I _{OUT} =0, EN=1, FB=105%*V _{REF}		65		μΑ
Shutdown Current	I _{SHDN H/W}	EN=0		2	2	
	I _{SHDN S/W}	EN=V _{IN} , Buck_ENx=0		41	Q	μA
EN, VSEL, SDA, SCL					5	
Rising threshold	V_{IH}		1.1	X		V
Falling threshold	V _{IL}			\mathbf{O}^{+}	0.4	V
V _{OUT} Accuracy	V _{REG}	Forced PWM, V _{OUT} =VSEL0, default value	-1.5		+1.5	%
NFET R _{DS(ON)}	R _{DS(ON)N}			17		mΩ
PFET R _{DS(ON)}	R _{DS(ON)P}			28		mΩ
PMOS peak current limit	I _{LIM PEAK}		7.5			Α
NMOS peak current limit	I _{LIM VALLEY}	- Ar	6			Α
Internal soft-start time	t _{SS}			300		us
Min on time				40		ns
Oscillator Frequency	F _{OSC}			2.4		MHz
Thermal Shutdown				150		°C
Temperature	T_{SD}			130		-
Thermal Shutdown Hysteresis	T _{HYS}			15		°C
LX node discharge resistor	R _{DSH}			150		Ω
Input OVP shutdown		Rising threshold		6.15		V
	Vove	Falling threshold	5.5	5.85		V
Over voltage protection blanking time	Blanking			20		us

Note 1: Stresses beyond the 'Absolute Maximum Ratings' may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 2: θ JA is measured in the natural convection at T_A = 25°C on a low effective single layer thermal conductivity test board of IEDEC 51-3 thermal measurement standard.

Note3: The device is not guaranteed to function outside its operating conditions.



Enabling Function

The EN pin controls SY8827E start up. EN pin low to high transition starts the power up sequencer. If EN pin is low, the DC/DC converter will be turned off.

SY8827E allows software to enable of the regulator when EN is HIGH, via the BUCK_EN bits. BUCK_EN0 and BUCK_EN1 are both initialized HIGH in the registers.

F	Pins	Bi		
EN	VSEL	BUCK_EN0	BUCK_EN1	OUTPUT
0	Х	Х	Х	OFF
1	0	0	Х	OFF
1	0	1	Х	ON
1	1	Х	0	OFF
1	1	Х	1	ON

Hardware and Software Enable control table.

Input Over Voltage Protection Function

When the V_{IN} exceeds over voltage protection threshold, SY8827E will stop switching to protect the circuitry. An internal 20us blanking time filter helps to prevent the circuit from shutting down due to noise spikes.

I²C Interface

SY8827E features an I^2C interface that allow the HOST processor to control the output voltage achieve the DVS function. The I^2C interface supports clock speeds of up to 3.4MHz and uses standard I^2C commands. SY8827E always operates as a slave device, and is addressed using a 7-bit slave address followed by an 8th bit, which indicates whether the transaction is a read-operation or a write-operation. I^2C address of the SY8827E is set at the factory to 0xC0h.

START and STOP Conditions:

SY8827E is controlled via an I²C compatible interface. The START condition is a HIGH to LOW transition of the SDA line while SCL is HIGH. The STOP condition is a LOW to HIGH transition on the SDA line while SCL is HIGH. A STOP condition must be sent before each START condition. The I²C master always generates the START and STOP conditions.



Data Validity.

The data on the SDA line must be stable during the HIGH period of the SCL, unless generating a START or STOP condition. The HIGH or LOW state of the data line can only change when the clock signal on the SCL line is LOW.





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Acknowledge:

Each address and data transmission uses 9-clock pulses. The ninth pulse is the acknowledge bit (ACK). After the

START condition, the master sends 7-slave address bits and an R/W bit during the next 8-clock pulses. During the ninth clock pulse, the device that recognizes its own address holds the data line low to acknowledge. The acknowledge bit is also used by both the master and the slave to acknowledge receipt of register addresses and data.



Data Transactions:

All transactions start with a control byte sent from the I^2C master device. The control byte begins with a START condition, followed by 7-bits of slave address (<u>1100000x</u> for the SY8827E, this address can be changed if necessary)

followed by the 8th bit, R/W bit. The R/W bit is 0 for a write or 1 for a read. If any slave devices on the I^2C bus recognize their address, they will acknowledge by pulling the SDA line low for the last clock cycle in the control byte. If no slaves exist at that address or are not ready to communicate, the data line will be 1, indicating a Not Acknowledge condition. Once the control byte is sent, and SY8827E acknowledges it, the 2nd byte sent by the master must be a register address byte. The register address byte tells the SY8827E which register the master will write or read. Once the SY8827E receives a register address byte it responds with an acknowledge.





Register Settings:

1. VSEL0 (0x00)

Register Name				VSEL0
Address				0x00
Field	Bit	R/W	Default	Description
BUCK_EN0	7	R/W	1	Software buck enable. When EN pin is low, the regulator is off. When EN pin is high, BUCK_EN bit takes precedent.
MODE0	6	R/W	0	0=Allow auto-PFM mode during light load. 1=Forced PWM mode
NSEL0	5:0	R/W	101100 (V _{OUT} =1.15V)	000000 = 0.60V 000001 = 0.6125V 101100 = 1.15 V 111111=1.3875V
2. VSEL1 (0x01)				0

2. VSEL1 (0x01)

. VSELI (0x01)				
Register Name				VSEL1
Address			C	0x01
Field	Bit	R/W	Default 🔿	Description
BUCK_EN1	7	R/W		Software buck enable. When EN pin is low, the regulator is off. When EN pin is high, BUCK_EN bit takes precedent.
MODE1	6	R/W	1 der	0=Allow auto-PFM mode during light load. 1=Forced PWM mode
NSEL1	5:0	RWO	101100 (V _{OUT} =1.15V)	000000 = 0.60V 000001 = 0.6125V 101100 = 1.15 V
sileroy		k		111111=1.3875V



3. Control Register (0x02)

Register Name				Control Register
Address				0x02
Field	Bit	R/W	Default	Description
Output Discharge	7	R/W	1	0 = discharge resistor is disabled. 1 = discharge resistor is enabled.
Slew Rate	6:4	R/W	011=12.5mV/1.2us	Set the slew rate for positive voltage transitions. 000 = 12.5mV/0.15us 001 = 12.5mV/0.3us 010 = 12.5mV/0.6us 011 = 12.5mV/1.2us 100 = 12.5mV/2.4us 101 = 12.5mV/4.8us 110 = 12.5mV/9.6us 111 = 12.5mV/19.2us
Reserved	3:0	R/W	0000	Always reads back 0.
4. ID1 Register (l)x03)			ales

4. ID1 Register (0x03)

I IDI Register (0	100)			
Register Name				ID1 Register
Address			\diamond	0x03
Field	Bit	R/W	Default	Description
VENDOR	7:5	R	100	IC vendor code.
Reverved	4	R	0,00	Always reads back 0.
DIE_ID	3:0	R	Q000	
5. ID2 Register (0	x04)	cÓ	<u> </u>	
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5. ID2 Register (0x04)

Register Name		\mathbf{O}		ID2 Register	
Address		D •		0x04	
Field	Bit	R/W	Default	Description	
Reverved	7:4	R	0000	Always reads back 0.	
DIE_REV	3:0	R	1100		
silero	2				



6. PGOOD Register (0x05)

Register Name				PGOOD Register
Address				0x05
Field	Bit	R/W	Default	Description
PGOOD	7	R	0	1: Buck is enabled and soft-start is completed.
Reserved	6:0	R	000 0000	Always reads back 0.
silerov		Q Q	tidential	completed. Always reads back 0.



Typical Performance Characteristics













Operation

SY $\overline{8827E}$ is a high efficiency 2.4MHz synchronous step down DC/DC regulator IC capable of delivering up to 6A output currents. It can operate over a wide input voltage range from 2.5V to 5.5V and integrate main switch and synchronous switch with very low R_{DS (ON)} to minimize the conduction loss. The output voltage can be programmed from 0.6V to 1.3875V through I²C interface.

Applications Information

Because of the high integration in SY8827E, the application circuit based on this regulator IC is rather simple. Only input capacitor C_{IN} , output capacitor C_{OUT} , inductor L need to be selected for the targeted applications.

Input capacitor CIN

This ripple current through input capacitor is calculated as:

$$I_{\text{CIN}_{\text{RMS}}} = I_{\text{OUT}} \times \sqrt{D(1-D)}$$
(A)

This formula has a maximum at $V_{IN}=2 \times V_{OUT}$ condition, where $I_{CIN RMS}=I_{OUT}/2$.

With the maximum load current at 6A, a typical X5R or better grade ceramic capacitor with 6.3V rating and greater than 22uF capacitance can handle this ripple current well. To minimize the potential noise problem, place this ceramic capacitor really close to the VIN and GND pins. Care should be taken to minimize the loop area formed by C_{IN}, and VIN/GND pins.

Output capacitor Cour

Both steady state ripple and transient requirements must be taken into account when selecting this capacitor. For the best performance, it is recommended to use X5R or better grade ceramic capacitor with 6.3V rating and more than one 22μ F capacitor.

Output inductor L:

There are several considerations in choosing this inductor.

1) Choose the inductance to provide the desired ripple current. It is suggested to choose the ripple current to be about 40% of the maximum

average input current. The inductance is calculated as:

$$L = \frac{V_{OUT}(1 - V_{OUT}/V_{IN_MAX})}{F_{SW} \times I_{OUT_MAX} \times 40\%} (H)$$

where F_{SW} is the switching frequency and I_{OUT_MAX} is the maximum load current.

SY8827E is less sensitive to the ripple current variations. Consequently, the final choice of inductance can be slightly off the calculation value without significantly impacting the performance.

2) The saturation current rating of an inductor must be selected to guarantee an adequate margin to the peak inductor current under full load conditions.

Isat, MIN > IOUT, MAX +
$$\frac{V_{OUT}(1-V_{OUT}/V_{IN,MAX})}{2 \cdot F_{SW} \cdot L}$$

3) The DOR of the inductor and the core loss at the switching frequency must be low enough to achieve the desired efficiency requirement. It is desirable to choose an inductor with DCR<15m Ω to achieve a good overall efficiency.

Layout Design:

To achieve a higher efficiency and better noise immunity, following components should be placed close to the IC: C_{IN} , L, C_{OUT} .

1) It is desirable to maximize the PCB copper area connecting to GND pin to achieve the best thermal and noise performance. Reasonable vias are suggested to be placed underneath the ground pad to enhance the soldering quality and thermal performance.

2) The decoupling capacitor of VIN and GND must be placed close enough to the pins. The loop area formed by the capacitors and GND must be minimized.

3) The PCB copper area associated with SW pin must be minimized to improve the noise immunity.

4) The feedback trace connecting C_{OUT} to the VOUT pin must NOT be adjacent to the SW node on the PCB layout to minimize the noise coupling to VOUT pin.



PCB Layout Suggestion











Notes: All dimension in MM and exclude mold flash & metal bur